







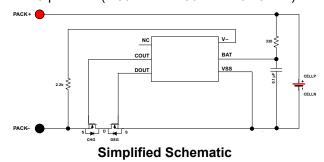


BQ2970, BQ2971, BQ2972, BQ2973 SLUSBU9H - MARCH 2014 - REVISED JUNE 2021

# BQ297xx Cost-Effective Voltage and Current Protection Integrated Circuit for Single-**Cell Li-Ion and Li-Polymer Batteries**

#### 1 Features

- Input voltage range pack+: VSS 0.3 V to 12 V
- FET drive:
  - CHG and DSG FET drive output
- Voltage sensing across external FETs for overcurrent protection (OCP) is within ±5 mV (typical)
- Fault detection
  - Overcharge detection (OVP)
  - Over-discharge detection (UVP)
  - Charge overcurrent detection (OCC)
  - Discharge overcurrent detection (OCD)
  - Load short-circuit detection (SCP)
- Zero voltage charging for depleted battery
- Factory programmed fault protection thresholds
  - Fault detection voltage thresholds
  - Fault trigger timers
  - Fault recovery timers
- Modes of operation without battery charger
  - NORMAL mode  $I_{CC} = 4 \mu A$
  - Shutdown Iq = 100 nA
- Operating temperature range  $T_A = -40$ °C to +85°C
- Package:
  - 6-pin DSE (1.50 mm × 1.50 mm × 0.75 mm)



# 2 Applications

- **Tablet PCs**
- Mobile handsets
- Handheld data terminals

# 3 Description

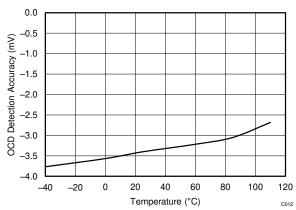
The BQ2970 battery cell protection device provides an accurate monitor and trigger threshold for overcurrent protection during high discharge/charge current operation or battery overcharge conditions.

The BQ2970 device provides the protection functions for Li-ion/Li-polymer cells, and monitors across the external power FETs for protection due to high charge or discharge currents. In addition, there is overcharge and depleted battery monitoring and protection. These features are implemented with low current consumption in NORMAL mode operation.

#### **Device Information**

| PART NUMBER                       | PACKAGE <sup>(1)</sup> | BODY SIZE (NOM)   |
|-----------------------------------|------------------------|-------------------|
| BQ2970, BQ2971,<br>BQ2972, BQ2973 | WSON (6)               | 1.50 mm × 1.50 mm |

For all available packages, see the orderable addendum at the end of the data sheet.



OCD Detection Accuracy Versus Temperature



# **Table of Contents**

| 1 Features                                     | 9 Detailed Description                  | 14              |
|--|---|-----------------|
| 2 Applications1                                | 9.1 Overview                            |                 |
| 3 Description                                  | 9.2 Functional Block Diagram            | 15              |
| 4 Revision History2                            | 9.3 Feature Description                 |                 |
| 5 Device Comparison Table3                     | 9.4 Device Functional Modes             |                 |
| 6 Pin Configuration and Functions3             | 10 Application and Implementation       |                 |
| 6.1 Pin Descriptions4                          | 10.1 Application Information            | 19              |
| 7 Specifications4                              | 10.2 Typical Application                |                 |
| 7.1 Absolute Maximum Ratings4                  | 11 Power Supply Recommendations         |                 |
| 7.2 ESD Ratings4                               | 12 Layout                               |                 |
| 7.3 Recommended Operating Conditions5          | 12.1 Layout Guidelines                  |                 |
| 7.4 Thermal Information5                       | 12.2 Layout Example                     |                 |
| 7.5 DC Characteristics5                        | 13 Device and Documentation Support     | <mark>23</mark> |
| 7.6 Programmable Fault Detection Thresholds 6  | 13.1 Related Documentation              | 23              |
| 7.7 Programmable Fault Detection Timer Ranges6 | 13.2 Support Resources                  | 23              |
| 7.8 Typical Characteristics7                   | 13.3 Trademarks                         |                 |
| 8 Parameter Measurement Information10          | 13.4 Electrostatic Discharge Caution    | 23              |
| 8.1 Timing Charts10                            | 13.5 Glossary                           |                 |
| 8.2 Test Circuits                              | 14 Mechanical, Packaging, and Orderable |                 |
| 8.3 Test Circuit Diagrams14                    | Information                             | 23              |
| -  |   |                 |

# **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision G (December 2018) to Revision H (June 2021)    | Page |
|--|------|
| Changed the BQ29728 and BQ29737 devices to Production Data           | 3    |
| Changes from Revision F (December 2018) to Revision G (January 2020) | Page |
| Changed the Device Comparison Table                                  | 3    |



# **5 Device Comparison Table**

| PART NUMBER <sup>(1)</sup> | OVP (V)  | OVP DELAY (s)         | UVP (V) | UVP DELAY<br>(ms)   | OCC (V)             | OCC DELAY<br>(ms) | OCD (V)     | OCD<br>DELAY<br>(ms) | SCD (V)               | SCD DELAY (µs) |
|----------------------------|----------|-----------------------|---------|---------------------|---------------------|-------------------|-------------|----------------------|-----------------------|----------------|
| BQ29700                    | 4.275    | 1.25                  | 2.800   | 144                 | -0.100              | 8                 | 0.100       | 20                   | 0.5                   | 250            |
| BQ29701                    | 4.280    | 1.25                  | 2.300   | 144                 | -0.100              | 8                 | 0.125       | 8                    | 0.5                   | 250            |
| BQ29702                    | 4.350    | 1                     | 2.800   | 96                  | -0.155              | 8                 | 0.160       | 16                   | 0.3                   | 250            |
| BQ29703                    | 4.425    | 1.25                  | 2.300   | 20                  | -0.100              | 8                 | 0.160       | 8                    | 0.5                   | 250            |
| BQ29704                    | 4.425    | 1.25                  | 2.500   | 20                  | -0.100              | 8                 | 0.125       | 8                    | 0.5                   | 250            |
| BQ29705                    | 4.425    | 1.25                  | 2.500   | 20                  | -0.100              | 8                 | 0.150       | 8                    | 0.5                   | 250            |
| BQ29706                    | 3.850    | 1.25                  | 2.500   | 144                 | -0.150              | 8                 | 0.200       | 8                    | 0.6                   | 250            |
| BQ29707                    | 4.280    | 1                     | 2.800   | 96                  | -0.090              | 6                 | 0.090       | 16                   | 0.3                   | 250            |
| BQ29716                    | 4.425    | 1.25                  | 2.300   | 20                  | -0.100              | 8                 | 0.165       | 8                    | 0.5                   | 250            |
| BQ29717                    | 4.425    | 1.25                  | 2.500   | 20                  | -0.100              | 8                 | 0.130       | 8                    | 0.5                   | 250            |
| BQ29718                    | 4.425    | 1.25                  | 2.500   | 20                  | -0.100              | 8                 | 0.100       | 8                    | 0.5                   | 250            |
| BQ29723                    | 4.425    | 1                     | 2.500   | 96                  | -0.060              | 4                 | 0.100       | 8                    | 0.3                   | 250            |
| BQ29728                    | 4.280    | 1.25                  | 2.800   | 144                 | -0.100              | 8                 | 0.150       | 8                    | 0.5                   | 250            |
| BQ29729                    | 4.275    | 1.25                  | 2.300   | 20                  | -0.100              | 8                 | 0.130       | 8                    | 0.5                   | 250            |
| BQ29732                    | 4.280    | 1.25                  | 2.500   | 144                 | -0.100              | 8                 | 0.190       | 8                    | 0.5                   | 250            |
| BQ29733                    | 4.400    | 1.25                  | 2.800   | 20                  | -0.100              | 8                 | 0.120       | 8                    | 0.3                   | 250            |
| BQ29737                    | 4.250    | 1                     | 2.800   | 96                  | -0.050              | 16                | 0.100       | 16                   | 0.3                   | 250            |
| BQ297xy                    | 3.85-4.6 | 0.25, 1,<br>1.25, 4.5 | 2.0–2.8 | 20, 96, 125,<br>144 | -0.045 to<br>-0.155 | 4, 6, 8, 16       | 0.090-0.200 | 8, 16, 20,<br>48     | 0.3, 0.4, 0.5,<br>0.6 | 250            |

<sup>(1)</sup> All of the protections have a recovery delay time. The recovery timer starts as soon as the fault is triggered. The device starts to check for a recovery condition only when the recovery timer expires. This is NOT a delay time between recovery condition to FETs recovery.

OVP recovery delay = 12 ms; UVP/OCC/OCD recovery delay = 8 ms.

# **6 Pin Configuration and Functions**

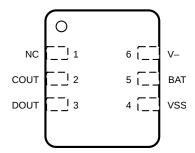


Figure 6-1. DSE Package 6-PIN WSON Top View

**Table 6-1. Pin Functions** 

| PIN  |     | TYPE | DESCRIPTION   |  |  |  |
|------|-----|------|---|--|--|--|
| NAME | NO. | IIPE | JESCRIP HON   |  |  |  |
| BAT  | 5   | Р    | VDD pin   |  |  |  |
| COUT | 2   | 0    | Gate Drive Output for Charge FET                                |  |  |  |
| DOUT | 3   | 0    | Gate Drive Output for Discharge FET                             |  |  |  |
| NC   | 1   | NC   | No Connection (electrically open, do not connect to BAT or VSS) |  |  |  |
| VSS  | 4   | Р    | Ground pin  |  |  |  |
| V-   | 6   | I/O  | Input pin for charger negative voltage                          |  |  |  |



## **6.1 Pin Descriptions**

## 6.1.1 Supply Input: BAT

This pin is the input supply for the device and is connected to the positive terminal of the battery pack. A 0.1-µF input capacitor is connected to ground for filtering noise.

#### 6.1.2 Cell Negative Connection: VSS

This pin is an input to the device for cell negative ground reference. Internal circuits associated with cell voltage measurements and overcurrent protection input to differential amplifier for either Vds sensing or external sense resistor sensing will be referenced to this node.

#### 6.1.3 Voltage Sense Node: V-

This is a sense node used for measuring several fault detection conditions, such as overcurrent charging or overcurrent discharging configured as Vds sensing for protection. This input, in conjunction with VSS, forms the differential measurement for the stated fault detection conditions. A 2.2-k $\Omega$  resistor is connected between this input pin and Pack– terminal of the system in the application.

#### 6.1.4 Discharge FET Gate Drive Output: DOUT

This pin is an output to control the discharge FET. The output is driven from an internal circuitry connected to the BAT supply. This output transitions from high to low when a fault is detected, and requires the DSG FET to turn OFF. A 5-M $\Omega$  high impedance resistor is connected from DOUT to VSS for gate capacitance discharge when the FET is turned OFF.

#### 6.1.5 Charge FET Gate Drive Output: COUT

This pin is an output to control the charge FET. The output is driven from an internal circuitry connected to the BAT supply. This output transitions from high to low when a fault is detected, and requires the CHG FET to turn OFF. A 5-M $\Omega$  high impedance resistor is connected from COUT to Pack– for gate capacitance discharge when FET is turned OFF.

# 7 Specifications

# 7.1 Absolute Maximum Ratings

|                                       |  | MIN <sup>(1)</sup> | MAX       | UNIT |
|---------------------------------------|--|--------------------|-----------|------|
|                                       | Input voltage: BAT   | -0.3               | 12        | V    |
| Supply control and input              | V- pin(pack-)  BAT - 28  BAT + 0.3  DOUT (Discharge FET Output), GDSG (Discharge FET Gate Drive)  VSS - 0.3  BAT + 0.3 | BAT + 0.3          | V         |      |
|                                       | DOUT (Discharge FET Output), GDSG (Discharge FET Gate Drive)   | VSS - 0.3          | BAT + 0.3 | V    |
| FET drive and protection              | COUT (Charge FET Output), GCHG (Charge FET Gate Drive)   | BAT – 28           | BAT + 0.3 | V    |
|                                       | Operating temperature: T <sub>FUNC</sub>   | -40                | 85        | °C   |
| Storage temperature, T <sub>stg</sub> | erature, T <sub>stg</sub> –55 150  |                    |           | °C   |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods can affect device reliability.

#### 7.2 ESD Ratings

|   |  |   | VALUE | UNIT |
|---|--|---|-------|------|
|   | Floatrostatio  | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(2)</sup> | ±2000 |      |
| V <sub>ESD</sub> <sup>(1)</sup> Electrostatic Discharge | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(3)</sup> | ±500  | V     |      |

<sup>(1)</sup> Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges into the device.

<sup>(2)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as 1000 V can have higher performance.

<sup>(3)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as 250 V can have higher performance.



# 7.3 Recommended Operating Conditions

|                          |  | MIN         | MAX | UNIT |
|--------------------------|--|-------------|-----|------|
| Supply control and input | Positive input voltage: BAT  | -0.3        | 8   | V    |
| Supply control and input | and input Negative input voltage: V- BAT – 25 BAT  Discharge FET control: DOUT VSS BAT | BAT         | V   |      |
| FET drive and protection | Discharge FET control: DOUT  | VSS         | BAT | V    |
|                          | Charge FET control: COUT   | BAT – 25    | BAT | V    |
|                          | Operating temperature: T <sub>Amb</sub>  | -40         | 85  | °C   |
| Tomporature Datings      | Storage temperature: T <sub>S</sub>  | <b>-</b> 55 | 150 | °C   |
| Temperature Ratings      | Lead temperature (soldering 10 s)  |             | 300 | °C   |
|                          | Thermal resistance junction to ambient, $\theta_{JA}$                                  |             | 250 | °C/W |

# 7.4 Thermal Information

|                          |  | BQ297xx    |      |
|--------------------------|--|------------|------|
|                          | THERMAL METRIC <sup>(1)</sup>                | DSE (WSON) | UNIT |
|                          |  | 12 PINS    |      |
| R <sub>0JA, High K</sub> | Junction-to-ambient thermal resistance       | 190.5      | °C/W |
| R <sub>0JC(top)</sub>    | Junction-to-case(top) thermal resistance     | 94.9       | °C/W |
| R <sub>0JB</sub>         | Junction-to-board thermal resistance         | 149.3      | °C/W |
| ΨЈТ                      | Junction-to-top characterization parameter   | 6.4        | °C/W |
| ΨЈВ                      | Junction-to-board characterization parameter | 152.8      | °C/W |
| R <sub>θJC(bottom)</sub> | Junction-to-case(bottom) thermal resistance  | N/A        | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

## 7.5 DC Characteristics

Typical Values stated where  $T_A = 25^{\circ}C$  and BAT = 3.6 V. Min/Max values stated where  $T_A = -40^{\circ}C$  to 85°C, and BAT = 3 V to 4.2 V (unless otherwise noted)

|                         | PARAMETER                              | TEST CONDITIONS                                    | MIN | TYP                       | MAX | UNIT |
|-------------------------|--|--|-----|---------------------------|-----|------|
| Current co              | nsumption                              |  |     | •                         |     |      |
| V                       | Davisa aparating range                 | BAT – VSS  | 1.5 |                           | 8   | V    |
| V <sub>BAT</sub>        | Device operating range                 | BAT – V–   | 1.5 |                           | 28  | V    |
| I <sub>NORMAL</sub>     | Current consumption in NORMAL mode     | BAT = 3.8 V, V- = 0 V                              |     | 4                         | 5.5 | μA   |
| I <sub>Power_down</sub> | Current consumption in power down mode | BAT = V- = 1.5 V                                   |     |                           | 0.1 | μΑ   |
| FET Outpu               | t, DOUT and COUT                       |  |     |                           |     |      |
| V <sub>OL</sub>         | Charge FET low output                  | I <sub>OL</sub> = 30 μA, BAT = 3.8 V               |     | 0.4                       | 0.5 | V    |
| V <sub>OH</sub>         | Charge FET high output                 | I <sub>OH</sub> = -30 μA, BAT = 3.8 V              | 3.4 | 3.7                       |     | V    |
| V <sub>OL</sub>         | Discharge FET low output               | I <sub>OL</sub> = 30 μA, BAT = 2 V                 |     | 0.2                       | 0.5 | V    |
| V <sub>OH</sub>         | Discharge FET high output              | I <sub>OH</sub> = -30 μA, BAT = 3.8 V              | 3.4 | 3.7                       |     | V    |
| Pullup Inte             | rnal Resistance on V–                  |  |     |                           |     |      |
| R <sub>V-D</sub>        | Resistance between V– and VBAT         | V <sub>BAT</sub> = 1.8 V, V– = 0 V                 | 100 | 300                       | 550 | kΩ   |
| Current sir             | nk on V–                               |  | '   |                           |     |      |
| I <sub>V-S</sub>        | Current sink on V- to VSS              | V <sub>BAT</sub> = 3.8 V                           | 8   |                           | 24  | μA   |
| Load short              | detection on V–                        |  |     |                           |     |      |
| V <sub>short</sub>      | Short detection voltage                | $V_{BAT}$ = 3.8 V and $R_{PackN}$ = 2.2 k $\Omega$ | \   | V <sub>BAT</sub> –<br>1 V |     | V    |
| 0-V battery             | charge function                        |  |     |                           |     |      |
| V <sub>0CHG</sub>       | 0-V battery charging start voltage     | 0-V battery charging function allowed              | 1.7 |                           |     | V    |



# 7.5 DC Characteristics (continued)

Typical Values stated where  $T_A = 25^{\circ}C$  and BAT = 3.6 V. Min/Max values stated where  $T_A = -40^{\circ}C$  to 85°C, and BAT = 3 V to 4.2 V (unless otherwise noted)

| PARAMETER                           |  | TEST CONDITIONS                          |  | TYP | MAX  | UNIT |
|-------------------------------------|--|--|--|-----|------|------|
| 0-V battery charge inhibit function |  |  |  |     |      |      |
| V <sub>0INH</sub>                   | 0-V battery charging inhibit voltage threshold | 0-V battery charging function disallowed |  |     | 0.75 | V    |

# 7.6 Programmable Fault Detection Thresholds

| PARAMETER                   |   | CONDITION  |                                   | MIN         | TYP | MAX | UNIT |
|-----------------------------|---|--|-----------------------------------|-------------|-----|-----|------|
|                             |   | Factory Device Configuration: 3.85 V to                                | T <sub>A</sub> = 25°C             | -10         |     | 10  | mV   |
| V <sub>OVP</sub>            | Overcharge detection voltage  | 4.60 V in 50-mV steps  | T <sub>A</sub> = 0°C to<br>60°C   | -20         |     | 20  | mV   |
| V <sub>OVP-Hys</sub>        | Overcharge release hysteresis voltage   | 100 mV and (VSS – V–) > OCC (min) for 25°C                             | release, T <sub>A</sub> =         | -20         |     | 20  | mV   |
| V <sub>UVP</sub>            | Over-discharge detection voltage  | Factory Device Configuration: 2.00 V to 2 steps, T <sub>A</sub> = 25°C | .80 V in 50-mV                    | -50         |     | 50  | mV   |
| V <sub>UVP+Hys</sub>        | Over-discharge release hysteresis voltage   | 100 mV and (BAT – V–) > 1 V for release, T <sub>A</sub> = 25°C         |                                   | <b>–</b> 50 |     | 50  | mV   |
|                             | Discharging overcurrent detection voltage  Discharging overcurrent 200 mV in 5-mV steps | Factory Dovice Configuration: 90 mV to                                 | T <sub>A</sub> = 25°C             | -10         |     | 10  | mV   |
| 1 V 0 0 D                   |   | , ,  | T <sub>A</sub> = -40°C to<br>85°C | -15         |     | 15  | mV   |
| Release of V <sub>OCD</sub> | Release of discharging overcurrent detection voltage                                    | Release when BAT – V– > 1 V  |                                   |             | 1   |     | V    |
|                             | Charging evergurrent detection  | Factory Device Configuration: –45 mV to                                | T <sub>A</sub> = 25°C             | -10         |     | 10  | mV   |
| V <sub>OCC</sub>            | voltage   | –155 mV in 5-mV steps  | T <sub>A</sub> = -40°C to<br>85°C | <b>–</b> 15 |     | 15  | mV   |
| Release of V <sub>OCC</sub> | Release of overcurrent detection voltage  | Release when VSS – V− ≥ OCC (min)                                      |                                   |             | 40  |     | mV   |
| V <sub>SCC</sub>            | Short Circuit detection voltage   | Factory Device Configuration: 300 mV, 400 mV, 500 mV, 600 mV           | T <sub>A</sub> = 25°C             | -100        |     | 100 | mV   |
| V <sub>SCCR</sub>           | Release of Short Circuit detection voltage  | Release when BAT – V– ≥ 1 V  |                                   |             | 1   |     | V    |

# 7.7 Programmable Fault Detection Timer Ranges

|                   | PARAMETER                                    | CONDITION  | MIN  | TYP MAX | UNIT |
|-------------------|--|--|------|---------|------|
| t <sub>OVPD</sub> | Overcharge detection delay time              | Factory Device Configuration: 0.25 s, 1 s, 1.25 s, 4.5 s   | -20% | 20%     | s    |
| t <sub>UVPD</sub> | Over-discharge detection delay time          | Factory Device Configuration: 20 ms, 96 ms, 125 ms, 144 ms | -20% | 20%     | ms   |
| t <sub>OCDD</sub> | Discharging overcurrent detection delay time | Factory Device Configuration: 8 ms, 16 ms, 20 ms, 48 ms    | -20% | 20%     | ms   |
| toccd             | Charging overcurrent detection delay time    | Factory Device Configuration: 4 ms, 6 ms, 8 ms, 16 ms      | -20% | 20%     | ms   |
| t <sub>SCCD</sub> | Short Circuit detection delay time           | 250 μs (fixed)   | -50% | 50%     | μs   |



# 7.8 Typical Characteristics

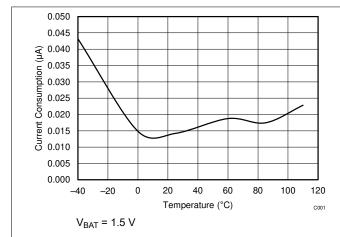


Figure 7-1. 1.5-V I<sub>BAT</sub> Versus Temperature

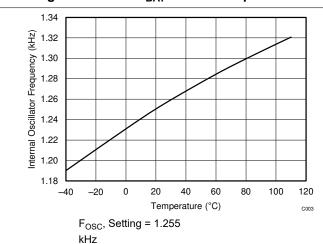


Figure 7-3. Internal Oscillator Frequency Versus Temperature

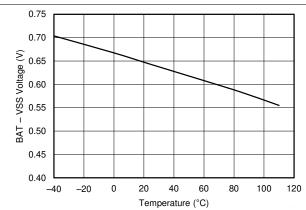


Figure 7-5. 0-V Charging Disallowed Versus Temperature

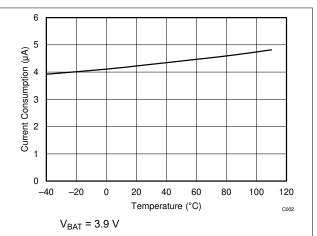


Figure 7-2. 3.9-V I<sub>BAT</sub> Versus Temperature

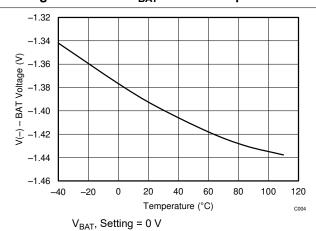


Figure 7-4. 0-V Charging Allowed Versus Temperature

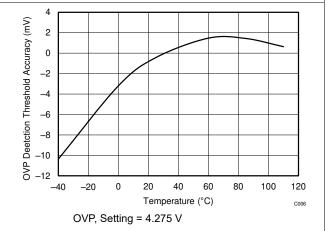
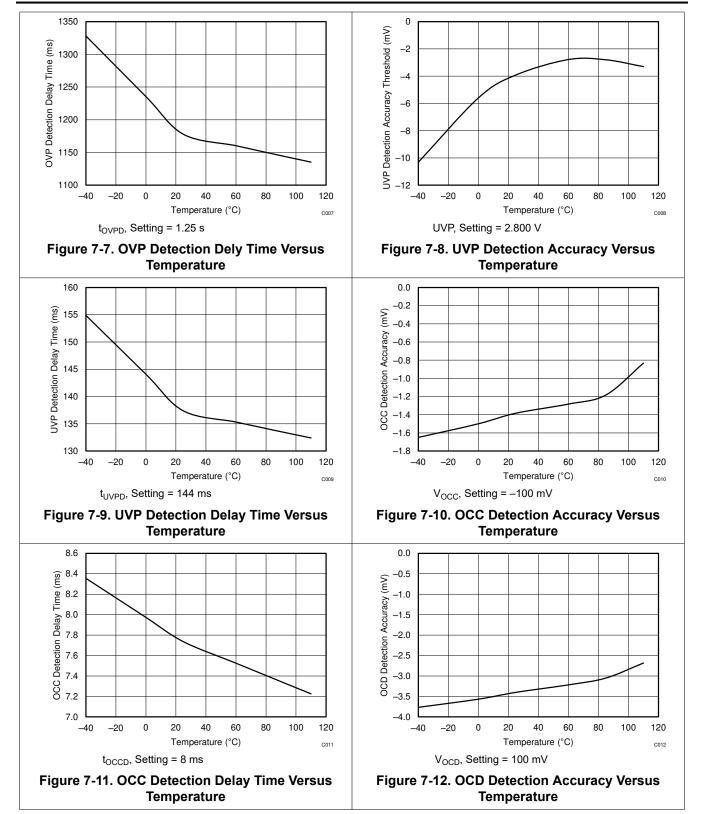


Figure 7-6. OVP Detection Accuracy Versus Temperature





1.10

-40

-20

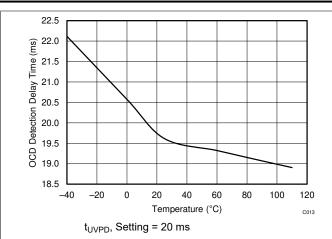


Figure 7-13. OCD Detection Delay Time Versus

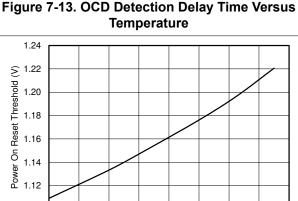


Figure 7-15. Power On Reset Versus Temperature

20

40

Temperature (°C)

60

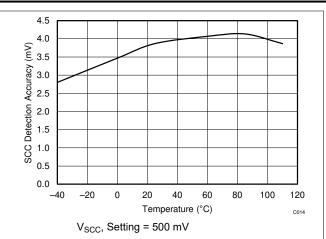


Figure 7-14. SCC Detection Accuracy Versus **Temperature** 

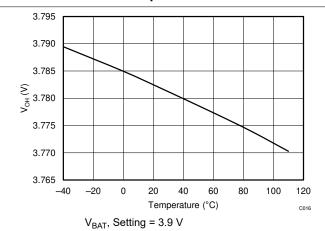
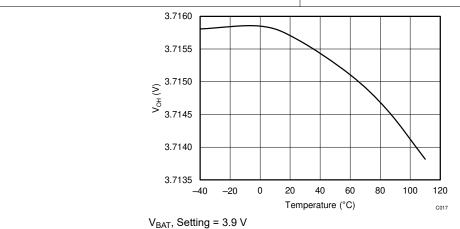


Figure 7-16. COUT Versus Temperature with Ioh = -30 µA



120

Figure 7-17. DOUT Versus Temperature with  $I_{oh}$  = -30  $\mu A$ 



# **8 Parameter Measurement Information**

# 8.1 Timing Charts

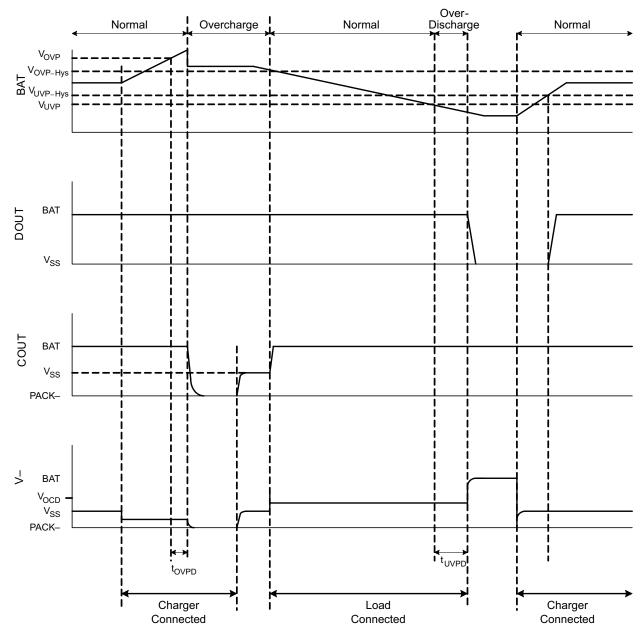


Figure 8-1. Overcharge Detection, Over-Discharge Detection



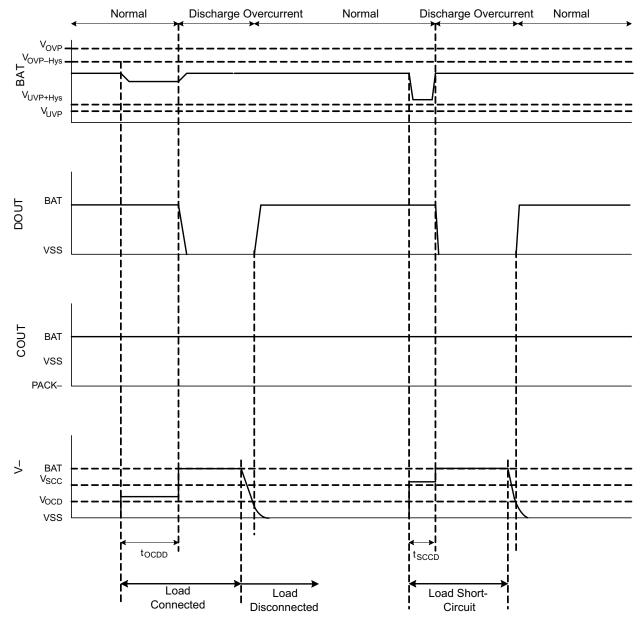


Figure 8-2. Discharge Overcurrent Detection

#### **8.2 Test Circuits**

The following tests are referenced as follows: The COUT and DOUT outputs are "H," which are higher than the threshold voltage of the external logic level FETs and regarded as ON state. "L" is less than the turn ON threshold for external NMOS FETs and regarded as OFF state. The COUT pin is with respect to V-, and the DOUT pin is with respect to VSS.

#### 1. Overcharge detection voltage and overcharge release voltage (Test Circuit 1):

The overcharge detection voltage ( $V_{OVP}$ ) is measured between the BAT and VSS pins, respectively. Once V1 is increased, the over-detection is triggered, and the delay timer expires. Then, COUT transitions from a high to low state and reduces the V1 voltage to check for the overcharge hysteresis parameter ( $V_{OVP-Hys}$ ). The delta voltage between overcharge detection voltages ( $V_{OVP}$ ) and the overcharge release occurs when the CHG FET drive output goes from low to high.

#### 2. Over-discharge detection voltage and over-discharge release voltage (Test Circuit 2):

Over-discharge detection ( $V_{UVP}$ ) is defined as the voltage between BAT and VSS at which the DSG drive output goes from high to low by reducing the V1 voltage. V1 is set to 3.5 V and gradually reduced while V2 is set to 0 V. The over-discharge release voltage is defined as the voltage between BAT and VSS at which the DOUT drive output transition from low to high when V1 voltage is gradually increased from a  $V_{UVP}$  condition. The overcharge hysteresis voltage is defined as the delta voltage between  $V_{UVP}$  and the instance at which the DOUT output drive goes from low to high.

#### 3. Discharge overcurrent detection voltage (Test Circuit 2):

The discharge overcurrent detection voltage ( $V_{OCD}$ ) is measured between V– and VSS pins and triggered when the V2 voltage is increased above  $V_{OCD}$  threshold with respect to VSS. This delta voltage once satisfied will trigger an internal timer  $t_{OCDD}$  before the DOUT output drive transitions from high to low.

## 4. Load short circuit detection voltage (Test Circuit 2):

Load short-circuit detection voltage ( $V_{SCC}$ ) is measured between V– and VSS pins and triggered when the V2 voltage is increased above  $V_{SCC}$  threshold with respect to VSS within 10  $\mu$ s. This delta voltage, once satisfied, triggers an internal timer  $t_{SCCD}$  before the DOUT output drive transitions from high to low.

#### 5. Charge overcurrent detection voltage (Test Circuit 2):

The charge overcurrent detection voltage ( $V_{OCC}$ ) is measured between VSS and V– pins and triggered when the V2 voltage is increased above  $V_{OCC}$  threshold with respect to V–. This delta voltage, once satisfied, triggers an internal timer  $t_{OCCD}$  before the COUT output drive transitions from high to low.

#### 6. Operating current consumption (Test Circuit 2):

The operating current consumption  $I_{BNORMAL}$  is the current measured going into the BAT pin under the following conditions: V1 = 3.9 V and V2 = 0 V.

# 7. Power down current consumption (Test Circuit 2):

The operating current consumption  $I_{Power\_down}$  is the current measured going into the BAT pin under the following conditions: V1 = 1.5 V and V2 = 1.5 V.

#### 8. Resistance between V- and BAT pin (Test Circuit 3):

Measure the resistance ( $R_{V_D}$ ) between V– and BAT pins by setting the following conditions: V1 = 1.8 V and V2 = 0 V.

#### 9. Current sink between V- and VSS (Test Circuit 3):

Measure the current sink  $I_{V-S}$  between V– and VSS pins by setting the following condition: V1 = 4 V.

#### 10. COUT current source when activated High (Test Circuit 4):

Measure  $I_{COUT}$  current source on the COUT pin by setting the following conditions: V1 = 3.9 V, V2 = 0 V, and V3 = 3.4 V.

#### 11. COUT current sink when activated Low (Test Circuit 4):

Measure  $I_{COUT}$  current sink on COUT pin by setting the following conditions: V1 = 4.5 V, V2 = 0 V, and V3 = 0.5 V.

#### 12. DOUT current source when activated High (Test Circuit 4):

Measure  $I_{DOUT}$  current source on DOUT pin by setting the following conditions: V1 = 3.9 V, V2 = 0 V, and V3 = 3.4 V.

#### 13. DOUT current sink when activated Low (Test Circuit 4):

Measure  $I_{DOUT}$  current sink on DOUT pin by setting the following conditions: V1 = 2.0 V, V2 = 0 V, and V3 = 0.4 V.

## 14. Overcharge detection delay (Test Circuit 5):

The overcharge detection delay time  $t_{OVPD}$  is the time delay before the COUT drive output transitions from high to low once the voltage on V1 exceeds the  $V_{OVP}$  threshold. Set V2 = 0 V and then increase V1 until BAT input exceeds the  $V_{OVP}$  threshold, then check the time for when COUT goes from high to low.

# 15. Over-discharge detection delay (Test Circuit 5):

The over-discharge detection delay time  $t_{UVPD}$  is the time delay before the DOUT drive output transitions from high to low once the voltage on V1 decreases to  $V_{UVP}$  threshold. Set V2 = 0 V and then decrease V1 until BAT input reduces to the  $V_{UVP}$ threshold, then check the time of when DOUT goes from high to low.

# 16. Discharge overcurrent detection delay (Test Circuit 5):

The discharge overcurrent detection delay time  $t_{OCDD}$  is the time for DOUT drive output to transition from high to low after the voltage on V2 is increased from 0 V to 0.35 V. V1 = 3.5 V and V2 starts from 0 V and increases to trigger threshold.

#### 17. Load short circuit detection delay (Test Circuit 5):

The load short-circuit detection delay time  $t_{SCCD}$  is the time for DOUT drive output to transition from high to low after the voltage on V2 is increased from 0 V to V1 – 1 V. V1 = 3.5 V and V2 starts from 0 V and increases to trigger threshold.

#### 18. Charge overcurrent detection delay (Test Circuit 5):

The charge overcurrent detection delay time  $t_{OCCD}$  is the time for COUT drive output to transition from high to low after the voltage on V2 is decreased from 0 V to -0.3 V. V1 = 3.5 V and V2 starts from 0 V and decreases to trigger threshold.

#### 19. 0-V battery charge starting charger voltage (Test Circuit 2):

The 0-V charge for start charging voltage  $V_{0CHA}$  is defined as the voltage between BAT and V– pins at which COUT goes high when voltage on V2 is gradually decreased from a condition of V1 = V2 = 0 V.

#### 20. 0-V battery charge inhibition battery voltage (Test Circuit 2):

The 0-V charge inhibit for charger voltage  $V_{0INH}$  is defined as the voltage between BAT and VSS pins at which COUT should go low as V1 is gradually decreased from V1 = 2 V and V2 = -4 V.

Copyright © 2021 Texas Instruments Incorporated



#### 8.3 Test Circuit Diagrams

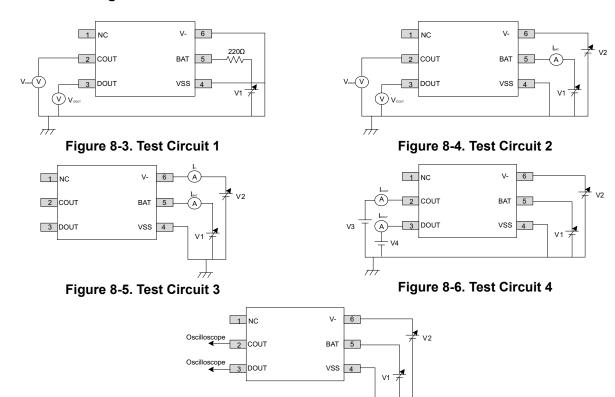


Figure 8-7. Test Circuit 5

# 9 Detailed Description

#### 9.1 Overview

This BQ2970 device is a primary protector for a single-cell Li-ion/Li-polymer battery pack. The device uses a minimum number of external components to protect for overcurrent conditions due to high discharge/charge currents in the application. In addition, it monitors and helps to protect against battery pack overcharging or depletion of energy in the pack. The BQ2970 device is capable of having an input voltage of 8 V from a charging adapter and can tolerate a voltage of BAT – 25 V across the two input pins. In the condition when a fault is triggered, there are timer delays before the appropriate action is taken to turn OFF either the CHG or DSG FETs. The recovery period also has a timer delay once the threshold for recovery condition is satisfied. These parameters are fixed once they are programmed. There is also a feature called zero voltage charging that enables depleted cells to be charged to an acceptable level before the battery pack can be used for normal operation. Zero voltage charging is allowed if the charger voltage is above 1.7 V. For Factory Programmable Options, see Table 9-1.

**Table 9-1. Factory Programmable Options** 

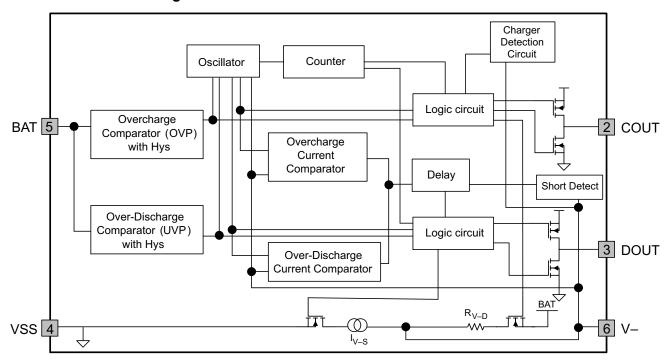
|                   | PARAMETER                                 | FACTORY DEVICE CONFIGURATION    |
|-------------------|---|---------------------------------|
| V <sub>OVP</sub>  | Overcharge detection voltage              | 3.85 V to 4.60 V in 50-mV steps |
| V <sub>UVP</sub>  | Over-discharge detection voltage          | 2.00 V to 2.80 V in 50-mV steps |
| V <sub>OCD</sub>  | Discharging overcurrent detection voltage | 90 mV to 200 mV in 5-mV steps   |
| V <sub>occ</sub>  | Charging overcurrent detection voltage    | -45 mV to -155 mV in 5-mV steps |
| V <sub>SCC</sub>  | Short Circuit detection voltage           | 300 mV, 400 mV, 500 mV, 600 mV  |
| t <sub>OVPD</sub> | Overcharge detection delay time           | 0.25 s, 1.00 s, 1.25 s, 4.50 s  |
| t <sub>UVPD</sub> | Over-discharge detection delay time       | 20 ms, 96 ms, 125 ms, 144 ms    |

**Table 9-1. Factory Programmable Options (continued)** 

|                   | PARAMETER                                    | FACTORY DEVICE CONFIGURATION |
|-------------------|--|------------------------------|
| t <sub>OCDD</sub> | Discharging overcurrent detection delay time | 8 ms, 16 ms, 20 ms, 48 ms    |
| t <sub>OCCD</sub> | Charging overcurrent detection delay time    | 4 ms, 6 ms, 8 ms, 16 ms      |
| t <sub>SCCD</sub> | Short Circuit detection delay time           | 250 µs (fixed)               |

For available released devices, see the *Released Device Configurations* table.

#### 9.2 Functional Block Diagram



#### 9.3 Feature Description

The BQ2970 family of devices measures voltage drops across several input pins for monitoring and detection of the following faults: OCC, OCD, OVP, and UVP. An internal oscillator initiates a timer to the fixed delays associated with each parameter once the fault is triggered. Once the timer expires due to a fault condition, the appropriate FET drive output (COUT or DOUT) is activated to turn OFF the external FET. The same method is applicable for the recovery feature once the system fault is removed and the recovery parameter is satisfied, then the recovery timer is initiated. If there are no reoccurrences of this fault during this period, the appropriate gate drive is activated to turn ON the appropriate external FET.

#### 9.4 Device Functional Modes

#### 9.4.1 Normal Operation

This device monitors the voltage of the battery connected between BAT pin and VSS pin and the differential voltage between V– pin and VSS pin to control charging and discharging. The system is operating in NORMAL mode when the battery voltage range is between the over-discharge detection threshold  $(V_{\text{UVP}})$  and the overcharge detection threshold  $(V_{\text{OCD}})$ , and the V– pin voltage is within the range for charge overcurrent threshold  $(V_{\text{OCD}})$  to over-discharge current threshold  $(V_{\text{OCD}})$  when measured with respect to VSS. If these conditions are satisfied, the device turns ON the drive for COUT and DOUT FET control.



#### CAUTION

When the battery is connected for the first time, the discharging circuit might not be enabled. In this case, short the V– pin to the VSS pin.

Alternatively, connect the charger between the Pack+ and Pack- terminals in the system.

# 9.4.2 Overcharge Status

This mode is detected when the battery voltage measured is higher than the overcharge detection threshold  $(V_{OVP})$  during charging. If this condition exists for a period greater than the overcharge detection delay  $(t_{OVPD})$  or longer, the COUT output signal is driven low to turn OFF the charging FET to prevent any further charging of the battery.

The overcharge condition is released if one of the following conditions occurs:

- If the V- pin is higher than the overcharge detection voltage (V<sub>OCC\_Min</sub>), the device releases the overcharge status when the battery voltage drops below the overcharge release voltage (V<sub>OVP-Hvs</sub>).
- If the V- pin is higher than or equal to the over-discharge detection voltage (V<sub>OCD</sub>), the device releases the
  overcharge status when the battery voltage drops below the overcharge detection voltage (V<sub>OVP</sub>).

The discharge is initiated by connecting a load after the overcharge detection. The V- pin rises to a voltage greater than VSS due to the parasitic diode of the charge FET conducting to support the load. If the V- pin voltage is higher than or equal to the discharge overcurrent detection threshold ( $V_{OCD}$ ), the overcurrent condition status is released only if the battery voltage drops lower than or equal to the overcharge detection voltage ( $V_{OVP}$ ).

#### **CAUTION**

- 1. If the battery is overcharged to a level greater than overcharge detection  $(V_{OVP})$  and the battery voltage does *not* drop below the overcharge detection voltage  $(V_{OVP})$  with a heavy load connected, the discharge overcurrent and load short-circuit detection features do *not* function until the battery voltage drops below the overcharge detection voltage  $(V_{OVP})$ . The internal impedance of a battery is in the order of tens of  $m\Omega$ , so application of a heavy load on the output should allow the battery voltage to drop immediately, enabling discharge overcurrent detection and load short-circuit detection features after an overcharge release delay.
- 2. When a charger is connected after an overcharge detection, the overcharge status does not release even if the battery voltage drops below the overcharge release threshold. The overcharge status is released when the V– pin voltage exceeds the overcurrent detection voltage (V<sub>OCD</sub>) by removing the charger.

## 9.4.3 Over-Discharge Status

If the battery voltage drops below the over-discharge detection voltage ( $V_{UVP}$ ) for a time greater than ( $t_{UVPD}$ ) the discharge control output, DOUT is switched to a low state and the discharge FET is turned OFF to prevent further discharging of the battery. This is referred to as an over-discharge detection status. In this condition, the V– pin is internally pulled up to BAT by the resistor  $R_{V-D}$ . When this occurs, the voltage difference between V– and BAT pins is 1.3 V or lower, and the current consumption of the device is reduced to power-down level  $I_{STANDBY}$ . The current sink  $I_{V-S}$  is not active in power-down state or over-discharge state. The power-down state is released when a charger is connected and the voltage delta between V– and BAT pins is greater than 1.3 V.

If a charger is connected to a battery in over-discharge state and the voltage detected at the V- is lower than -0.7~V, the device releases the over-discharge state and allows the DOUT pin to go high and turn ON the discharge FET once the battery voltage exceeds over-discharge detection voltage ( $V_{UVP}$ ).

If a charger is connected to a battery in over-discharge state and the voltage detected at the V- is higher than -0.7 V, the device releases the over-discharge state and allows the DOUT pin to go high and turn ON the discharge FET once the battery voltage exceeds over-discharge detection release hysteresis voltage  $(V_{\text{UVP}})_{\text{Hys}}$ .



#### 9.4.4 Discharge Overcurrent Status (Discharge Overcurrent, Load Short-Circuit)

When a battery is in normal operation and the V– pin is equal to or higher than the discharge overcurrent threshold for a time greater than the discharge overcurrent detection delay, the DOUT pin is pulled low to turn OFF the discharge FET and prevent further discharge of the battery. This is known as the discharge overcurrent status. In the discharge overcurrent status, the V– and VSS pins are connected by a constant current sink  $I_{V-S}$ . When this occurs and a load is connected, the V– pin is at BAT potential. If the load is disconnected, the V– pin goes to VSS (BAT/2) potential.

This device detects the status when the impedance between Pack+ and Pack- (see Figure 26) increases and is equal to the impedance that enables the voltage at the V- pin to return to BAT – 1 V or lower. The discharge overcurrent status is restored to the normal status.

Alternatively, by connecting the charger to the system, the device returns to normal status from discharge overcurrent detection status, because the voltage at the V– pin drops to BAT – 1 V or lower.

The resistance R<sub>V-D</sub> between V- and BAT is not connected in the discharge overcurrent detection status.

#### 9.4.5 Charge Overcurrent Status

When a battery is in normal operation status and the voltage at V- pin is lower than the charge overcurrent detection due to high charge current for a time greater than charge overcurrent detection delay, the COUT pin is pulled low to turn OFF the charge FET and prevent further charging to continue. This is known as charge overcurrent status.

The device is restored to normal status from charge overcurrent status when the voltage at the V– pin returns to charge overcurrent detection voltage or higher by removing the charger from the system.

The charge overcurrent detection feature does *not* work in the over-discharge status.

The resistance  $R_{V-D}$  between V- and BAT and the current sink  $I_{V-S}$  is not connected in the charge overcurrent status.

#### 9.4.6 0-V Charging Function Enabled

This feature enables recharging a connected battery that has very low voltage due to self-discharge. When the charger applies a voltage greater than or equal to  $V_{0CHG}$  to Pack+ and Pack- connections, the COUT pin gate drive is fixed by the BAT pin voltage.

Once the voltage between the gate and the source of the charging FET becomes equal to or greater than the turn ON voltage due to the charger voltage, the charging FET is ON and the battery is charged with current flow through the charging FET and the internal parasitic diode of the discharging FET. Once the battery voltage is equal to or higher than the over-discharge release voltage, the device enters normal status.

#### **CAUTION**

- 1. Some battery providers do not recommend charging a depleted (self-discharged) battery. Consult the battery supplier to determine whether to have the 0-V battery charger function.
- 2. The 0-V battery charge feature has a higher priority than the charge overcurrent detection function. In this case, the 0-V charging will be allowed and the battery charges forcibly, which results in charge overcurrent detection being disabled if the battery voltage is lower than the over-discharge detection voltage.

#### 9.4.7 0-V Charging Inhibit Function

This feature inhibits recharging a battery that has an internal short circuit of a 0-V battery. If the battery voltage is below the charge inhibit voltage  $V_{0INH}$  or lower, the charge FET control gate is fixed to the Pack– voltage to inhibit charging. When the battery is equal to  $V_{0INH}$  or higher, charging can be performed. The 0-V charge inhibit function is available in all configurations of the BQ297xx device.



#### **CAUTION**

Some battery providers do not recommend charging a depleted (self-discharged) battery. Consult the battery supplier to determine whether to enable or inhibit the 0-V battery charger function.

#### 9.4.8 Delay Circuit

The detection delay timers are based from an internal clock with a frequency of 10 kHz.

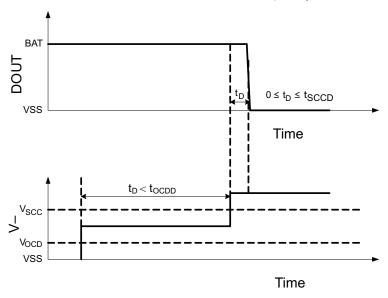


Figure 9-1. Delay Circuit

If the over-discharge current is detected, but remains below the over-discharge short circuit detection threshold, the over-discharge detection conditions must be valid for a time greater than or equal to over-discharge current delay  $t_{OCCD}$  time before the DOUT goes low to turn OFF the discharge FET. However, during any time the discharge overcurrent detection exceeds the short circuit detection threshold for a time greater than or equal to load circuit detection delay  $t_{SCCD}$ , the DOUT pin goes low in a faster delay for protection.



# 10 Application and Implementation

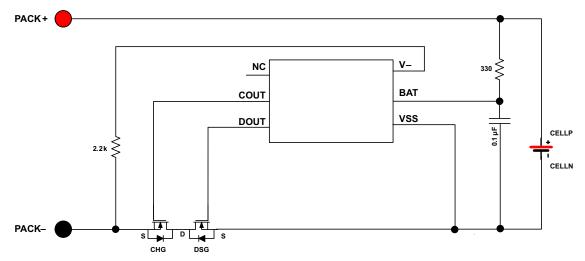
#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 10.1 Application Information

The BQ2970 devices are a family of primary protectors used for protection of the battery pack in the application. The application drives two low-side NMOS FETs that are controlled to provide energy to the system loads or interrupt the power in the event of a fault condition.

# 10.2 Typical Application



The 5-M resistor for an external gate-source is optional.

Figure 10-1. Typical Application Schematic, BQ2970

# 10.2.1 Design Requirements

For this design example, use the parameters listed in Table 10-1.

**Table 10-1. Design Parameters** 

| DESIGN PARAMETER                                  | EXAMPLE VALUE at T <sub>A</sub> = 25°C |
|---|--|
| Input voltage range                               | 4.5 V to 7 V                           |
| Maximum operating discharge current               | 7 A                                    |
| Maximum Charge Current for battery pack           | 4.5 A                                  |
| Overvoltage Protection (OVP)                      | 4.275 V                                |
| Overvoltage detection delay timer                 | 1.2 s                                  |
| Overvoltage Protection (OVP) release voltage      | 4.175 V                                |
| Undervoltage Protection (UVP)                     | 2.8 V                                  |
| Undervoltage detection delay timer                | 150 ms                                 |
| Undervoltage Protection (UVP) release voltage     | 2.9 V                                  |
| Charge Overcurrent detection (OCC) voltage        | −70 mV                                 |
| Charge Overcurrent Detection (OCC) delay timer    | 9 ms                                   |
| Discharge Overcurrent Detection (OCD) voltage     | 100 mV                                 |
| Discharge Overcurrent Detection (OCD) delay timer | 18 ms                                  |



Table 10-1. Design Parameters (continued)

| DESIGN PARAMETER   | EXAMPLE VALUE at T <sub>A</sub> = 25°C |
|--|--|
| Load Short Circuit Detection SCC) voltage, BAT to -V ≤ threshold | 500 mV                                 |
| Load Short Circuit Detection (SCC) delay timer                   | 250 μs                                 |
| Load Short Circuit release voltage, BAT to –V ≥ Threshold        | 1 V                                    |

#### 10.2.2 Detailed Design Procedure

#### Note

The external FET selection is important to ensure the battery pack protection is sufficient and complies to the requirements of the system.

- FET Selection: Because the maximum desired discharge current is 7 A, ensure that the Discharge Overcurrent circuit does *not* trigger until the discharge current is above this value.
- The total resistance tolerated across the two external FETs (CHG + DSG) should be 100 mV/7 A = 14.3 mΩ.
- Based on the information of the total ON resistance of the two switches, determine what would be the Charge Overcurrent Detection threshold, 14.3 mΩ × 4.5 A = 65 mV. Selecting a device with a 70-mV trigger threshold for Charge Overcurrent trigger is acceptable.
- The total Rds ON should factor in any worst-case parameter based on the FET ON resistance, de-rating due to temperature effects and minimum required operation, and the associated gate drive (Vgs). Therefore, the FET choice should meet the following criteria:

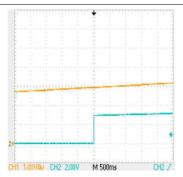
Vdss = 25 V

Each FET Rds ON =  $7.5 \text{ m}\Omega$  at Tj =  $25^{\circ}\text{C}$  and Vgs = 3.5 V

- Imax > 50 A to allow for short Circuit Current condition for 350 μs (max delay timer). The only limiting factor during this condition is Pack Voltage/(Cell Resistance + (2 × FET\_RdsON) + Trace Resistance).
- Use the CSD16406Q3 FET for the application.
- An RC filter is required on the BAT for noise, and enables the device to operate during sharp negative transients. The 330-Ω resistor also limits the current during a reverse connection on the system.
- TI recommends placing a high impedance 5-M $\Omega$  across the gate source of each external FET to deplete any charge on the gate-source capacitance.

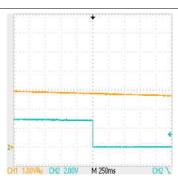


# 10.2.3 Application Performance Plots



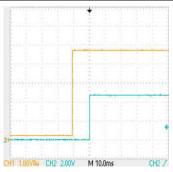
Orange Line (Channel 1) = Power Up Ramp on BAT Pin Turquoise Line (Channel 2) = DOUT Gate Drive Output DOUT goes from low to high when UVP Recovery = UVP Set Threshold +100 mV

Figure 10-2. UVP Recovery



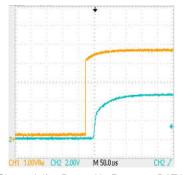
Orange Line (Channel 1) = Power Down Ramp on BAT Pin Turquoise Line (Channel 2) = DOUT Date Drive Output DOUT goes from high to low when UVP threshold = UVP set Threshold + set delay time

Figure 10-3. UVP Set Condition



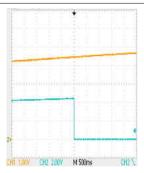
Orange Line (Channel 1) = Power Up Ramp on BAT pin Turquoise Line (Channel 2) = DOUT Gate Drive Output

Figure 10-4. Initial Power Up, DOUT



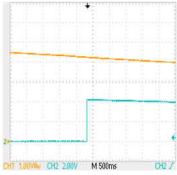
Orange Line (Channel 1) = Power Up Ramp on BAT Pin Turquoise Line (Channel 2) = COUT Gate Drive Output

Figure 10-5. Initial Power Up, COUT



Orange Line (Channel 1) = Power Up Ramp on BAT Pin Turquoise Line (Channel 2) = COUT Gate Drive Output COUT goes from high to low when OVP threshold = OVP set Threshold + set delay time

Figure 10-6. OVP Set Condition



Orange Line (Channel 1) = Decrease Voltage on BAT Pin Turquoise Line (Channel 2) = COUT Gate Drive Output COUT goes from low to high when OVP Recovery = OVP Set Threshold -100 mV

Figure 10-7. OVP Recovery Condition



# 11 Power Supply Recommendations

The recommended power supply for this device is a maximum 8-V operation on the BAT input pin.

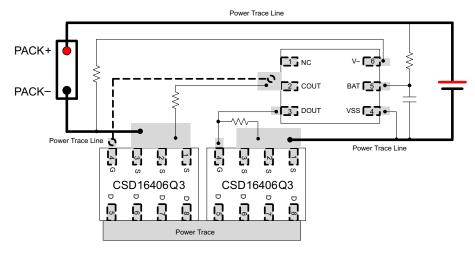
# 12 Layout

# 12.1 Layout Guidelines

The following are the recommended layout guidelines:

- 1. Ensure the external power FETs are adequately compensated for heat dissipation with sufficient thermal heat spreader based on worst-case power delivery.
- 2. The connection between the two external power FETs should be very close to ensure there is not an additional drop for fault sensing.
- 3. The input RC filter on the BAT pin should be close to the terminal of the IC.

## 12.2 Layout Example



Via connects between two layers

Figure 12-1. BQ2970 Board Layout



# 13 Device and Documentation Support

#### 13.1 Related Documentation

BQ29700 Single-Cell Li-Ion Protector EVM User's Guide (SLUUAZ3)

#### 13.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 13.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

## 13.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# 13.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



11-Jun-2021

www.ti.com

# **PACKAGING INFORMATION**

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| BQ29700DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FA                      | Samples |
| BQ29700DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FA                      | Samples |
| BQ29701DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FY                      | Samples |
| BQ29701DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FY                      | Samples |
| BQ29702DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FZ                      | Samples |
| BQ29702DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | FZ                      | Samples |
| BQ29703DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F1                      | Samples |
| BQ29703DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F1                      | Samples |
| BQ29704DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F2                      | Samples |
| BQ29704DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F2                      | Samples |
| BQ29705DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F3                      | Samples |
| BQ29705DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F3                      | Samples |
| BQ29706DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F4                      | Samples |
| BQ29706DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F4                      | Samples |
| BQ29707DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F5                      | Samples |
| BQ29707DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | F5                      | Samples |
| BQ29716DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3P                      | Samples |
| BQ29716DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3P                      | Samples |
| BQ29717DSER      | ACTIVE     | WSON         | DSE                | 6    | 3000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3Q                      | Samples |
| BQ29717DSET      | ACTIVE     | WSON         | DSE                | 6    | 250            | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3Q                      | Samples |

# PACKAGE OPTION ADDENDUM

www.ti.com 11-Jun-2021

| Orderable Device | Status    | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan       | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|-----------|--------------|--------------------|------|----------------|----------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| D000740D0ED      | 4.OTI) /F | MOON         | DOE                |      | 0000           | Dallo a Ossass | (6)                           | 1 1 4 0000 HINH IM | 40.1- 05     | 0.0                     |         |
| BQ29718DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3R                      | Samples |
| BQ29718DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3R                      | Samples |
| BQ29723DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3S                      | Samples |
| BQ29723DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3S                      | Samples |
| BQ29728DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | EJ                      | Samples |
| BQ29728DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | EJ                      | Samples |
| BQ29729DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3Т                      | Samples |
| BQ29729DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3Т                      | Samples |
| BQ29732DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3U                      | Samples |
| BQ29732DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 3U                      | Samples |
| BQ29733DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 4Q                      | Samples |
| BQ29733DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | 4Q                      | Samples |
| BQ29737DSER      | ACTIVE    | WSON         | DSE                | 6    | 3000           | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | EI                      | Samples |
| BQ29737DSET      | ACTIVE    | WSON         | DSE                | 6    | 250            | RoHS & Green   | NIPDAU                        | Level-1-260C-UNLIM | -40 to 85    | EI                      | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



# PACKAGE OPTION ADDENDUM

www.ti.com 11-Jun-2021

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



www.ti.com 12-Jun-2021

# TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

| A0 | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| D1 | Pitch between successive cavity centers                   |

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



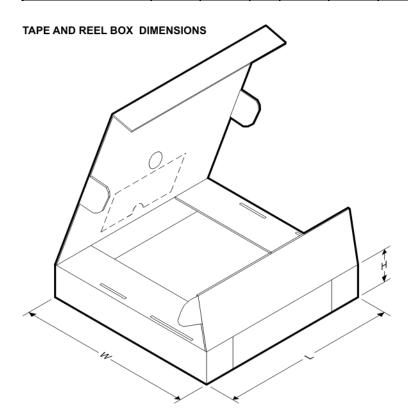
\*All dimensions are nominal

| Device      | Package<br>Type | Package<br>Drawing | Pins | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ29700DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29700DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29701DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29701DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29702DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29702DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29703DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29703DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29704DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29704DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29705DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29705DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29706DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29706DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29707DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29707DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29716DSER | WSON            | DSE                | 6    | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29716DSET | WSON            | DSE                | 6    | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |



www.ti.com 12-Jun-2021

| Device      | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ29717DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29717DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29718DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29718DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29723DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29723DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29728DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29728DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29729DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29729DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29732DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29732DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29733DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29733DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29737DSER | WSON            | DSE                | 6 | 3000 | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |
| BQ29737DSET | WSON            | DSE                | 6 | 250  | 180.0                    | 8.4                      | 1.75       | 1.75       | 1.0        | 4.0        | 8.0       | Q2               |



# \*All dimensions are nominal

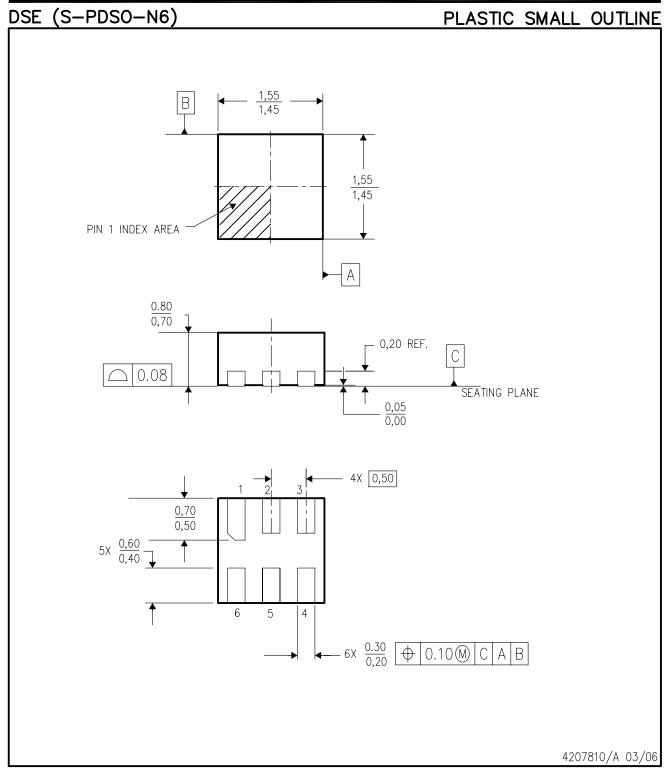
| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ29700DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |



# **PACKAGE MATERIALS INFORMATION**

www.ti.com 12-Jun-2021

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ29700DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29701DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29701DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29702DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29702DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29703DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29703DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29704DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29704DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29705DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29705DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29706DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29706DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29707DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29707DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29716DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29716DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29717DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29717DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29718DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29718DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29723DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29723DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29728DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29728DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29729DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29729DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29732DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29732DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29733DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29733DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| BQ29737DSER | WSON         | DSE             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| BQ29737DSET | WSON         | DSE             | 6    | 250  | 182.0       | 182.0      | 20.0        |



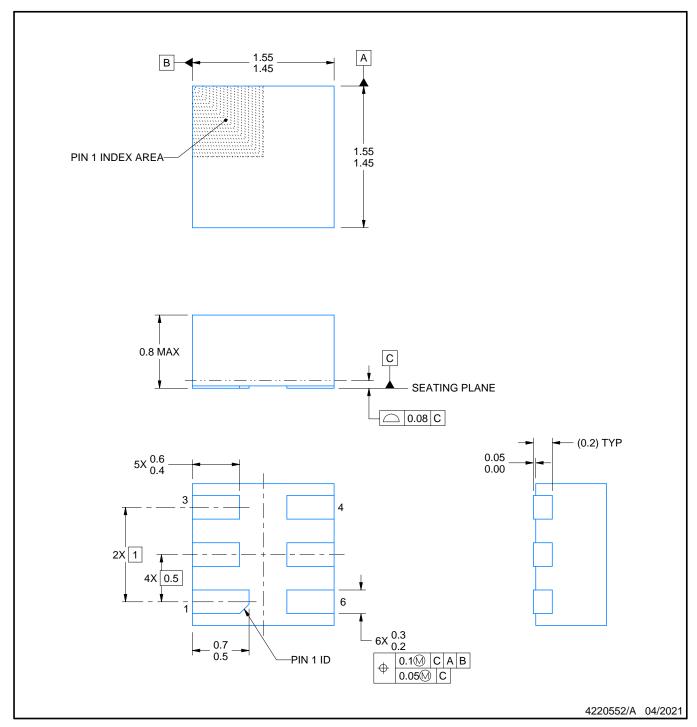
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Small Outline No-Lead (SON) package configuration.
- D. This package is lead-free.





PLASTIC SMALL OUTLINE - NO LEAD



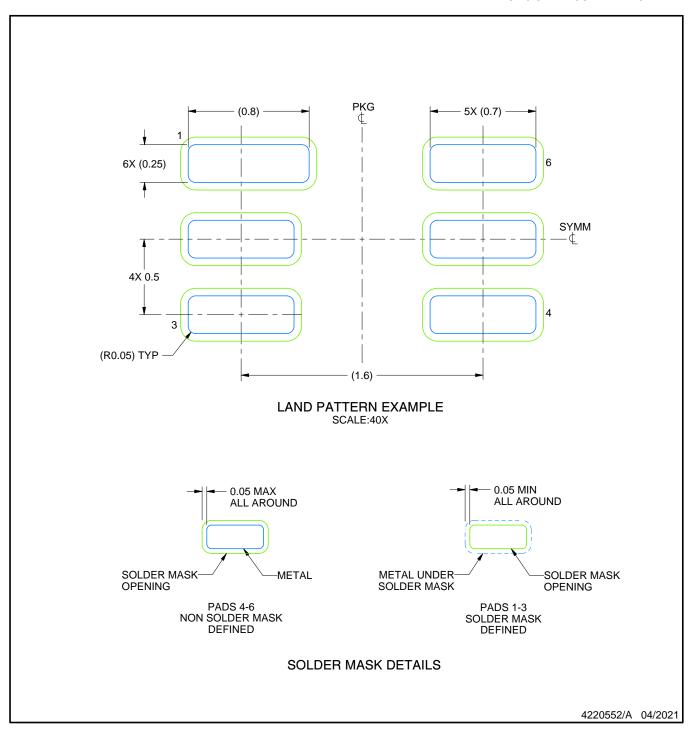
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



PLASTIC SMALL OUTLINE - NO LEAD

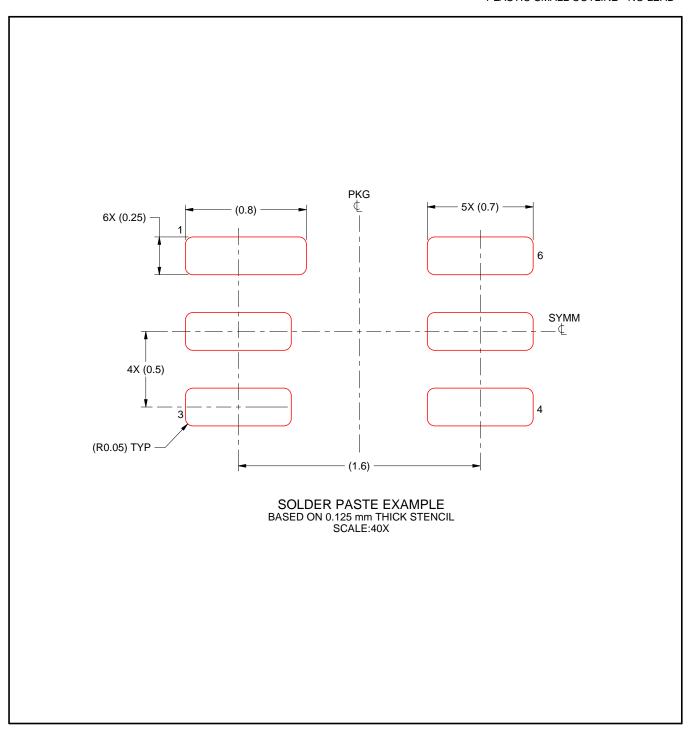


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (https://www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021, Texas Instruments Incorporated